

N-Channel 80V MOSFET

E080N8P7CH1

| V_{DS} (V) | $R_{DS(on),max}$ (m Ω) | I_D (A) |
|--------------|--------------------------------|-----------|
| 80V | 8.7 @ $V_{GS} = 10V$ | 80 |

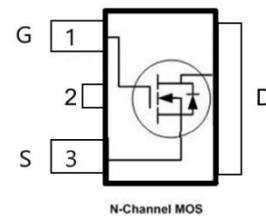
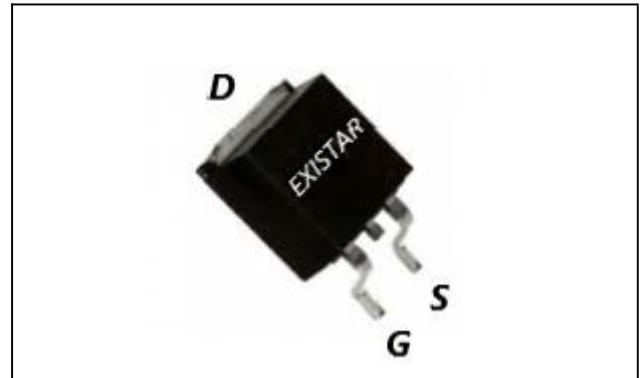
Features

- Low $R_{DS(on)}$ trench technology
- Low thermal impedance
- Fast switching speed
- 100% avalanche tested

Applications

- DC/DC conversion
- Power switch
- PD charger
- Moto driver

TO-252



Package And Ordering Information

| Ordering code | Package | Marking |
|---------------|---------|-------------|
| E080N8P7CH1 | TO-252 | E080N8P7CH1 |

Ordering Information

| Package | Units/ Reel | Reels/ Inner Box | Units/ Inner Box |
|---------|-------------|------------------|------------------|
| TO-252 | 2500 | 1 | 2500 |

Key Performance Parameters

| Parameter | Value | Unit |
|--|-------|------|
| V _{DS} , min @ T _j (max) | 80 | V |
| I _D , pulse | 324 | A |
| R _{DS(ON)} , max @ V _{GS} =10V | 8.7 | mΩ |
| Q _g | 112 | nC |

Absolute Maximum Ratings at T_j=25°C Unless Otherwise Noted

| Parameter | | Symbol | Limit | Unit |
|--|-----------------------|-----------------------------------|------------|------|
| Drain-source voltage | | V _{DS} | 80 | V |
| Gate-source voltage | | V _{GS} | ±20 | |
| Continuous drain current | T _C =25°C | I _D | 80 | A |
| | T _C =100°C | | 51 | |
| Pulsed drain current | | I _{D,pulse} | 324 | |
| Avalanche energy, single pulse | | E _{AS} | 361 | mJ |
| Power dissipation | T _C =25°C | P _D | 125 | W |
| | T _C =100°C | | 50 | |
| Operating junction and storage temperature range | | T _J , T _{stg} | -55 To 150 | °C |

Thermal Characteristics

| Parameter | | Symbol | Max. | Unit |
|---|--------------|------------------|------|------|
| Thermal resistance, junction-to-case | Steady state | R _{θJC} | 1 | °C/W |
| Thermal resistance, junction-to-ambient | Steady state | R _{θJA} | - | |

Electrical Characteristics at T_j=25°C unless otherwise specified

| Parameter | Symbol | Min. | Typ. | Max. | Unit | Test conditions |
|-----------------------------------|----------------------|------|------|------|------|---|
| Static | | | | | | |
| Drain to source breakdown voltage | V _{(BR)DSS} | 80 | | | V | V _{GS} = 0, I _D = 250 μA |
| Gate-source threshold voltage | V _{GS(th)} | 2 | 2.8 | 4 | V | V _{DS} = V _{GS} , I _D = 250 μA |
| Gate-body leakage | I _{GSS} | | | ±100 | nA | V _{DS} = 0 V, V _{GS} = ±20 V |
| Zero gate voltage drain current | I _{DSS} | | | 1 | μA | V _{DS} = 80 V, V _{GS} = 0 V |
| Drain-source on-resistance | R _{DS(on)} | | 7.5 | 8.7 | mΩ | V _{GS} = 10 V, I _D = 40 A |
| | | | 9 | 11.2 | mΩ | V _{GS} = 6 V, I _D = 20 A |
| Forward transconductance | g _{fs} | | 36 | | S | V _{DS} = 10 V, I _D = 40 A |

| | | | | | | |
|------------------------------|---------|--|------|-----|----|---|
| Gate resistance | Rg | | 0.65 | | Ω | f=1MHz |
| Gate Charge | | | | | | |
| Total gate charge | Qg | | 112 | | nC | VDS = 40 V, ID = 20 A, VGS = 10 V |
| Gate-source charge | Qgs | | 15 | | | |
| Gate-drain charge | Qgd | | 45 | | | |
| Dynamic | | | | | | |
| Turn-on delay time | td(on) | | 30 | | ns | VDS = 40 V, VGS = 10 V, RL = 2 Ω, RGEN = 6 Ω |
| Rise time | tr | | 18 | | | |
| Turn-off delay time | td(off) | | 65 | | | |
| Fall time | tf | | 30 | | | |
| Input capacitance | Ciss | | 4400 | | pF | VDS =40 V, VGS = 0 V, f = 1.0MHz |
| Output capacitance | Coss | | 197 | | | |
| Reverse transfer capacitance | Crss | | 171 | | | |
| Body Diode | | | | | | |
| Diode forward voltage | VSD | | | 1.2 | V | VGS = 0 V, IF = 20 A |
| Reverse recovery time | trr | | 7 | | ns | Is =20 A, di/dt = 100 A/μs |
| Reverse recovery charge | Qrr | | 40 | | nC | |

Electrical Characteristics Diagrams

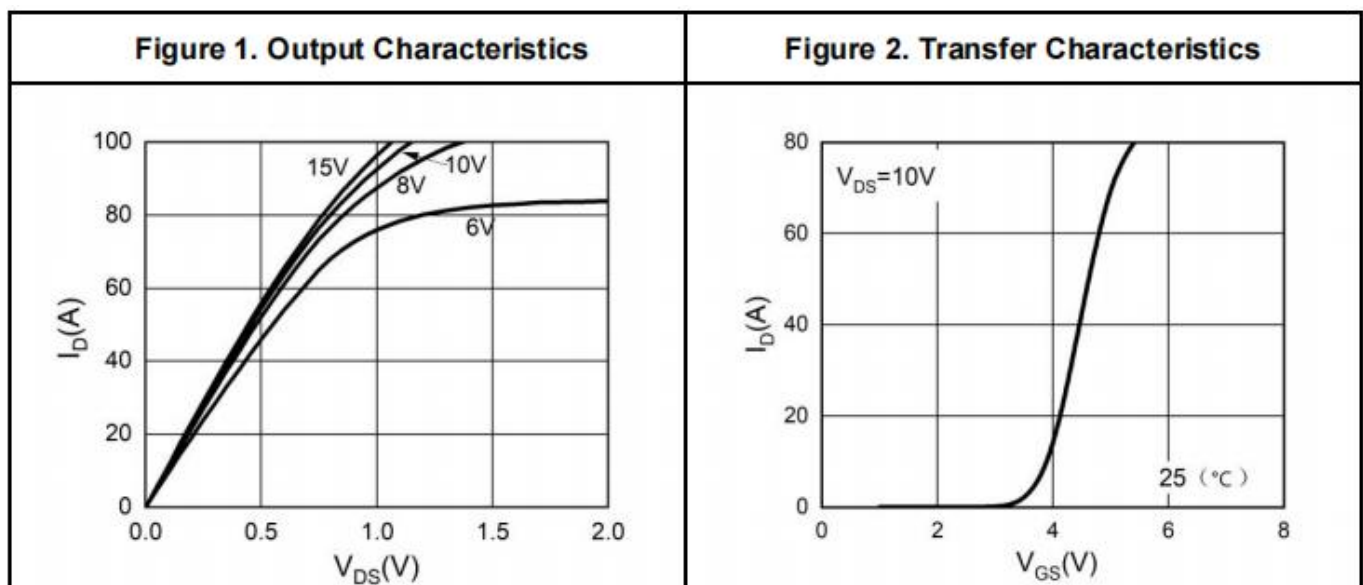


Figure 3. Power Dissipation

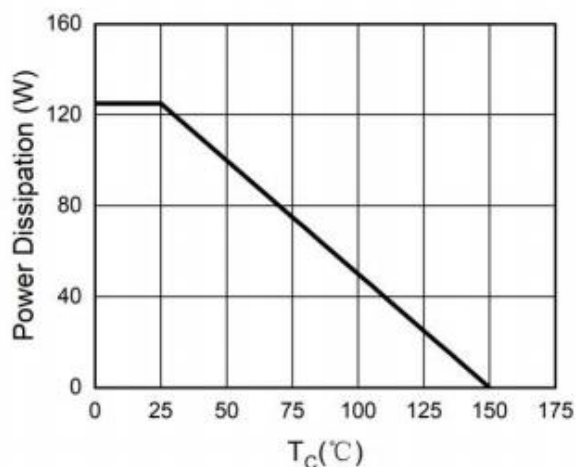


Figure 4. Drain Current

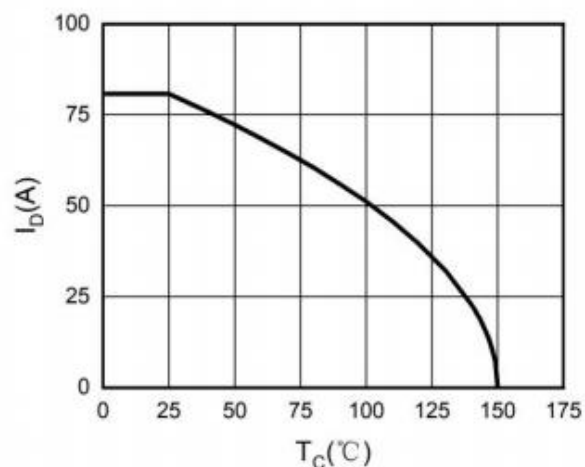


Figure 5. BV_{DSS} vs Junction Temperature

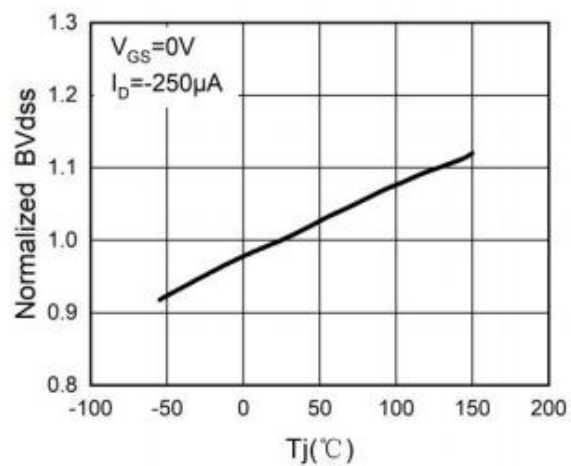


Figure 6. $R_{DS(ON)}$ vs Junction Temperature

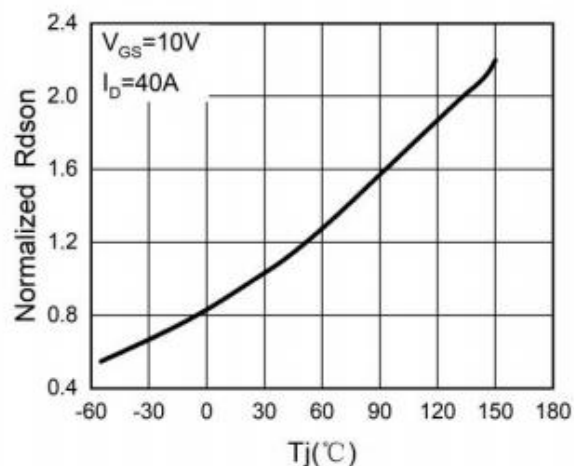
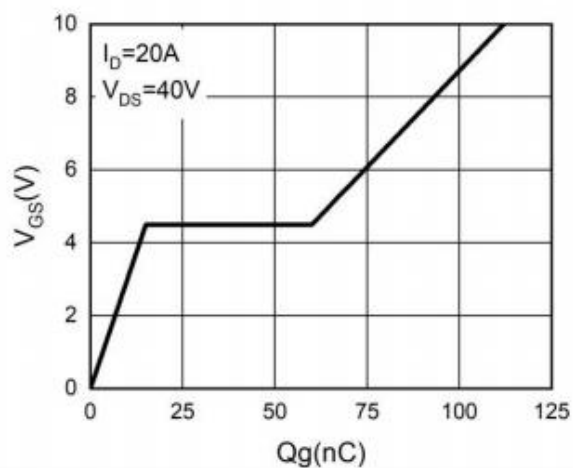
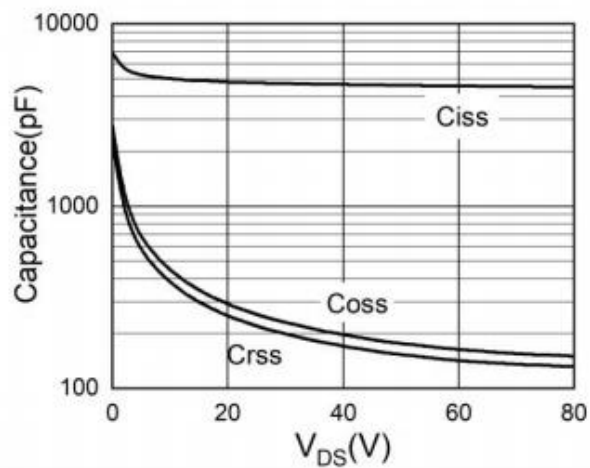
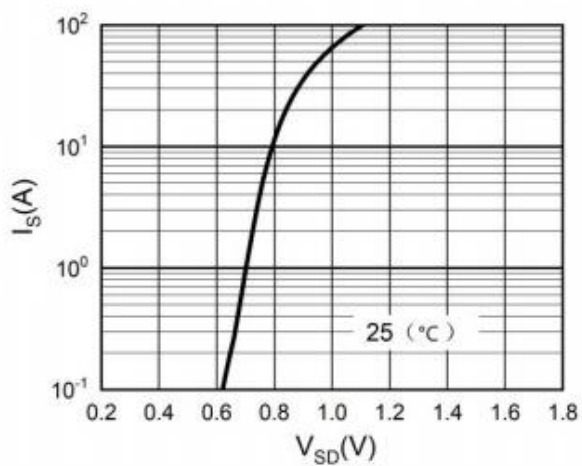
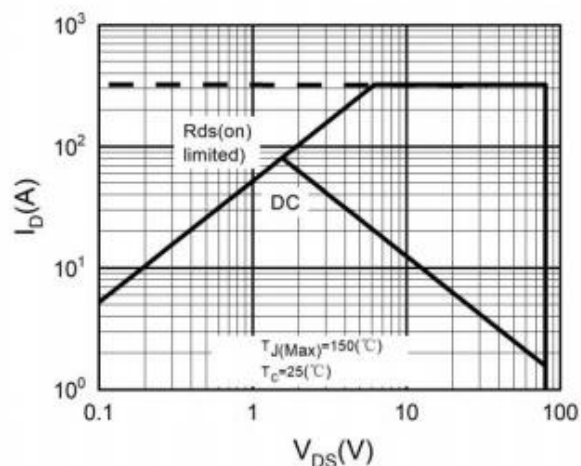
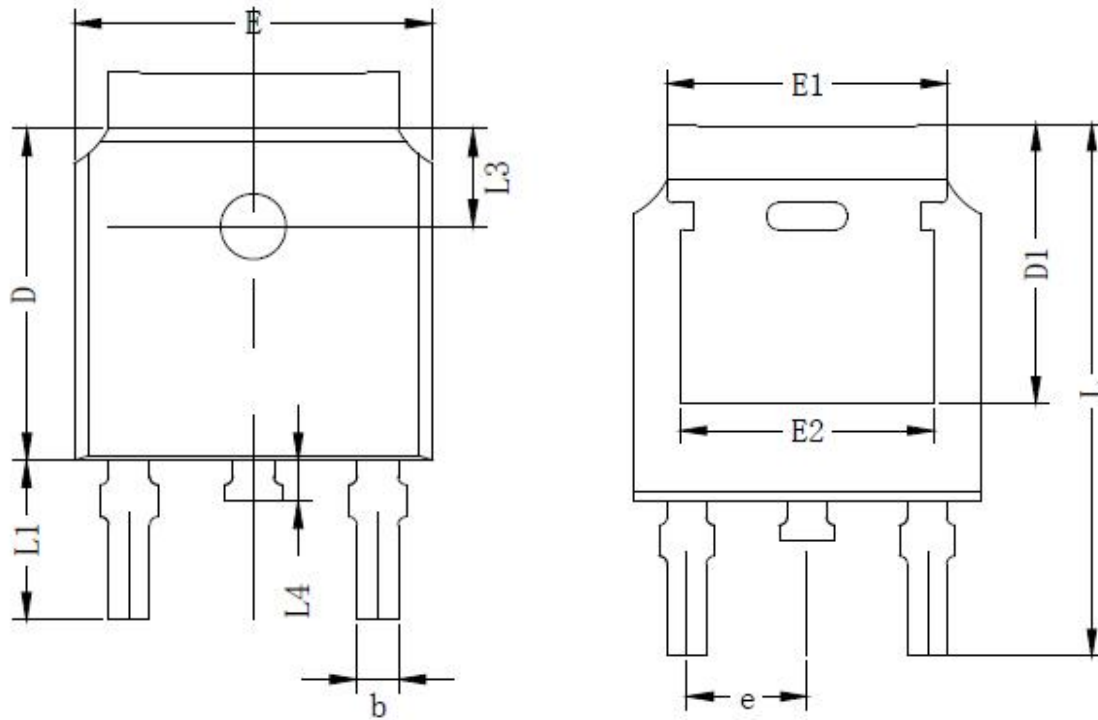


Figure 7. Gate Charge Waveforms

Figure 8. Capacitance

Figure 9. Body-Diode Characteristics

Figure 10. Maximum Safe Operating Area


Package Outline Dimensions



| SYMBOL | MIN | NOM | MAX |
|--------|-----------|-------|-------|
| A | 2.10 | 2.30 | 2.50 |
| A1 | 0.97 | 1.07 | 1.17 |
| A2 | 0.00 | — | 0.12 |
| b | 0.66 | 0.76 | 0.86 |
| c | 0.45 | 0.51 | 0.60 |
| D | 5.90 | 6.10 | 6.30 |
| D1 | 5.10 | 5.30 | 5.45 |
| E | 6.40 | 6.60 | 6.80 |
| E1 | 5.10 | 5.33 | 5.45 |
| E2 | 4.63 | 4.83 | 5.03 |
| L | 9.90 | 10.10 | 10.30 |
| L1 | 2.74 | 2.94 | 3.14 |
| L2 | 1.40 | 1.50 | 1.70 |
| L3 | 1.65 | 1.80 | 1.95 |
| L4 | 0.60 | 0.80 | 1.00 |
| e | 2.286 BSC | | |
| θ | 5° | 7° | 10° |
| θ1 | 0° | — | 3° |

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